






	<h2>FFD10UP20S</h2>
	<p>Hersteller-Teilenummer: FFD10UP20S</p> <p>Hersteller / Marke: AMI Semiconductor / ON Semiconductor</p> <p>Teil der Beschreibung: DIODE GEN PURP 200V 10A DPAK</p> <p>Datenblätter:  FFD10UP20S.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 18977 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	FFD10UP20S
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	DIODE GEN PURP 200V 10A DPAK
Kategorie	Diskrete Halbleiterprodukte > Dioden-Gleichrichter-
Teilstatus	18977 pcs Stock
detaillierte Beschreibung	Diode Standard 200V 10A Surface Mount TO-252, (D-
Serie	-
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-252-3, DPak (2 Leads + Tab), SC-63
Supplier Device-Gehäuse	TO-252, (D-Pak)
Diodentyp	Standard
Strom - Richt (Io)	10A
Spannung - Forward (Vf) (Max) @ If	1.15V @ 10A
Strom - Sperrleckstrom @ Vr	100µA @ 200V
Spannung - Sperr (Vr) (max)	200V
Geschwindigkeit	Fast Recovery = 200mA (Io)
Rückwärts-Erholzeit (Trr)	20.8ns
Betriebstemperatur - Anschluss	-65°C ~ 175°C
Kapazität @ Vr, F	-
Verpackung	Tape & Reel (TR)
Basisteilenummer	FFD10UP20
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)
Andere Namen	FFD10UP20STR

FFD10UP20S ist neu im Original, Suche FFD10UP20S Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FFD10UP20S AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage FFD10UP20S: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>FFD06UP20S FDK America DIODE GEN PURP 200V 6A DPAK</p>	 <p>FFD20UP20S AMI Semiconductor / ON Semiconductor DIODE GEN PURP 200V 20A DPAK</p>	 <p>FFD08S60S_F085 Fairchild/ON Semiconductor FFD08S60S_F085 Fairchild/ON Semiconductor</p>	 <p>FFD04H60S Fairchild/ON Semiconductor DIODE GEN PURP 600V 4A DPAK</p>
 <p>FFD10UP20S Fairchild/ON Semiconductor DIODE GEN PURP 200V 10A DPAK</p>	 <p>FFD08S60S Original FFD08S60S Original</p>	 <p>FFD20UP20S Fairchild/ON Semiconductor DIODE GEN PURP 200V 20A DPAK</p>	 <p>FFD06UP20S Fairchild/ON Semiconductor DIODE GEN PURP 200V 6A DPAK</p>

heiße Teile

Mehr

 AD6438BST	 AD7814ARMZ	 AP2822CKTR-G1	 AZ431AZ-BTRE1	 C3216CH2J681K085AA
 CC1808KKX7RDBB102	 CGA2B3X5R1E104M050BB	 CGA4J3X5R1H474K125AB	 CS18LV10245CCR55	 CTT116GK18
 CY74FCT573ATSOC	 DS25BR120TSD/NOPB	 E74HA3.7B-G	 FD1200R17KF6C_B2	 FFD06UP20S
 FFD06UP20S	 FFD08S60S	 FFD08S60S-F085	 FFD08S60S_F085	 FFD10UP20S
 FFD20UP20S	 FFD20UP20S	 GRM32DR71E106KA12K	 HMC194MS8E	 HXS50-NP
 IDH08SG60C	 IXFK50N85X	 K438F5091	 K6X1008T2D-PF70	 KSD471AGTA
 KST4403MTF	 MAX8674EWN+T	 MFS201NSW	 MMBD7000-7-F	 MP1591DN
 MPC8541EPXAPF	 NL322522T-R27K-3	 P2803NVG	 PS2521L-1-E4-A	 QHW075F871
 R920181100	 SK25DGD065ET	 SM4T18A-TR	 SN74HC595ANSR	 SP490EEP-L
 SW36CXC680	 TC74HC4538AP	 TLV2352IDRG4	 TT500N18KOF	 VE-J02-EX

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